

Vishay Siliconix

N-Channel 200 V (D-S) MOSFET



PRODUCT SUMMARY						
V _{DS} (V)	200					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 10 \text{ V}$	0.130					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 6 \text{ V}$	0.142					
Q _g typ. (nC)	20					
I _D (A)	4.1					
Configuration	Single					

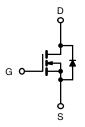
FEATURES

- TrenchFET® power MOSFETs
- New low thermal resistance PowerPAK® package with low 1.07 mm profile
- · PWM optimized for fast switching



APPLICATIONS

• Primary side switch



N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8
Lead (Pb)-free	Si7462DP-T1-E3
Lead (Pb)-free and halogen-free	Si7462DP-T1-GE3

ABSOLUTE MAXIMUM RATINGS	Γ _A = 25 °C, unl	ess otherwise	noted)			
PARAMETER		SYMBOL	10 s	STEADY STATE	UNIT	
Drain-source voltage		V_{DS}	200	200	M	
Gate-source voltage		V_{GS}	± 20	± 20	V	
Continuous drain current (T _J = 150 °C) ^a	T _A = 25 °C	,	4.1	2.6		
	T _A = 85 °C	I _D	3	1.9		
Pulsed drain current		I _{DM}	12	12	Α	
Avalanche current	L = 0.1 mH	I _{AS}	6	6		
Single avalanche energy (duty cycle ≤ 1 %)	Single avalanche energy (duty cycle ≤ 1 %)		1.8	1.8	mJ	
Continuous source current (diode conduction) a		I _S	4	1.6	Α	
Maximum navvay dissination 3	T _A = 25 °C	Б	4.8	1.9	W	
Maximum power dissipation ^a	T _A = 85 °C	P_{D}	2.6	1	VV I	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150		°C	
Soldering recommendations (peak temperature) b, c		-	2			

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^a	t ≤ 10 s	٥	21	26	
Maximum junction-to-ambient "	Steady state	R_{thJA}	55	65	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	1.7	2.1	

Notes

- a. Surface mounted on 1" x 1" FR4 board
- b. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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SPECIFICATIONS (T _J = 25°	C, unless	otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	4	V	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
Zava gata valtaga drain avreant		V _{DS} = 200 V, V _{GS} = 0 V	-	-	1		
Zero gate voltage drain current	I _{DSS}	V _{DS} = 200 V, V _{GS} = 0 V, T _J = 85 °C		20	μΑ		
On-state drain current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	12	-	=	Α	
Drain aguros en etata registance à	В	V _{GS} = 10 V, I _D = 4.1 A	-	0.110	0.130	A Ω S V	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 6 V, I _D = 3.9 A	-	0.120	0.142		
Forward transconductance a	9 _{fs}	V _{DS} = 15 V, I _D = 4.1 A	-	13	-	S	
Diode forward voltage ^a	V_{SD}	I _S = 4 A, V _{GS} = 0 V	-	0.8	1.2	V	
Dynamic ^b							
Total gate charge	Q_g		-	20	30		
Gate-source charge	Q_{gs}	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 4.1 \text{ A}$	-	4.5	-	nC	
Gate-drain charge	Q_{gd}		-	6.5	-		
Gate resistance	R_g		-	2	=	Ω	
Turn-on delay time	t _{d(on)}		-	15	25		
Rise time	t _r	$V_{DD} = 100 \text{ V}, R_1 = 100 \Omega$	-	15	25		
Turn-off delay time	t _{d(off)}	$I_D \cong \overline{1}$ A, $V_{GEN} = \overline{10}$ V, $R_g = 6$ Ω	-	40	60	ns	
Fall time	t _f		-	20	30		
Source-drain reverse recovery time	t _{rr}	I _F = 4 A, di/dt = 100 A/μs	-	70	110		

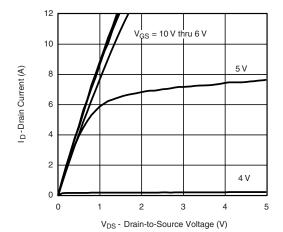
Notes

- a. Pulse test: pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing

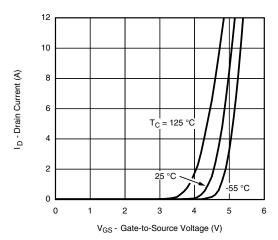
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



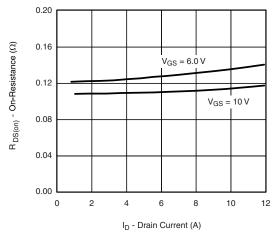
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



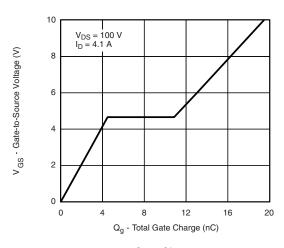
Output Characteristics



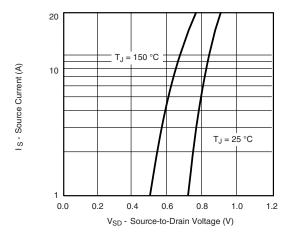
Transfer Characteristics



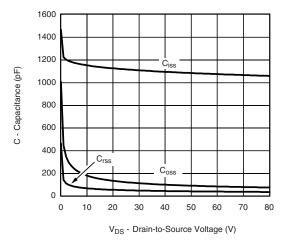
On-Resistance vs. Drain Current



Gate Charge

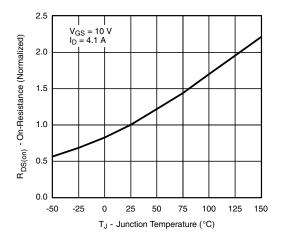


Source-Drain Diode Forward Voltage

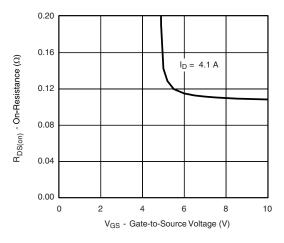




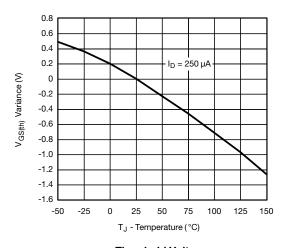
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



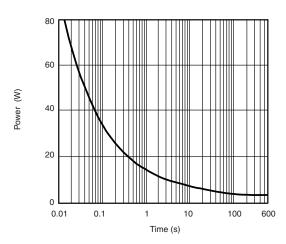
On-Resistance vs. Junction Temperature



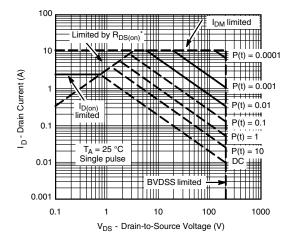
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



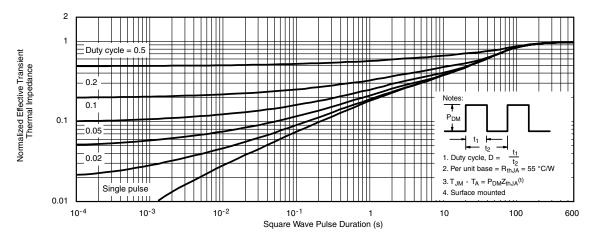
Single Pulse Power



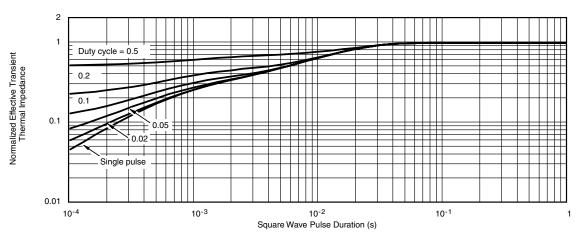
Safe Operating Area



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



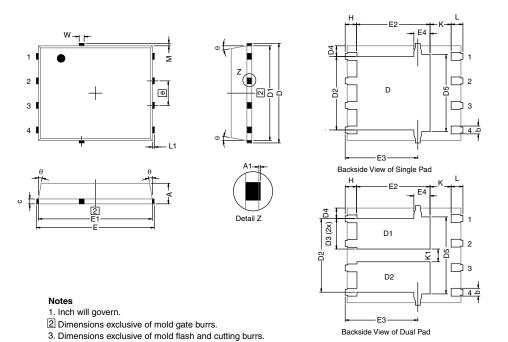
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72136.



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.20	
D1	4.80	4.90	5.00	0.189	0.193	0.19	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.		0.0225 typ.			
D5		3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.23	
E2	3.48	3.66	3.84	0.137	0.144	0.15	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4		0.75 typ.			0.030 typ.		
е		1.27 BSC		0.050 BSC			
K		1.27 typ.			0.050 typ.		
K1	0.56	-	=	0.022	=	=	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М		0.125 typ.			0.005 typ.		

Revison: 13-Feb-17 1 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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